Synchrotrons, X-rays, and Energy Related Research

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Outline

- Introduction
 - Synchrotron Radiation
- Experimental
 - Photoemission & X-ray Absorption
- Ag Clusters
- Radiation Damage
- O CdTe Solar Cells
- Acknowledgements

COLLABORATORS

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Synchrotrons

RALCAMPUS

CONFEDENCE CENTERS

RF / EXTRACTION BLDG.~

BOOSTER/ INJECTOR

LOW-ENERGY UNDULATOR TEST LINE

EXPERIMENT HALL

det i danble en cesti d

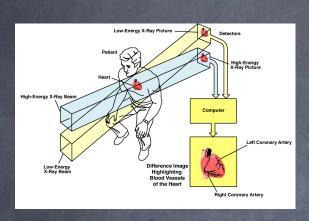
STORAGERING

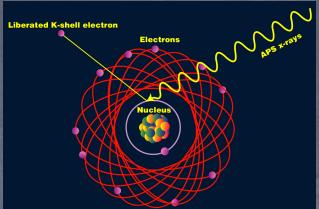
LAB/OFFICE MODULES

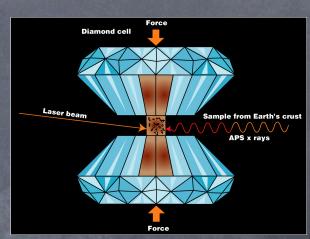
LINAC/INJECTION BLDG.

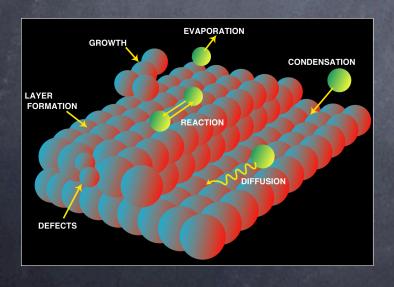
LAB/OFFICE MODULES

Synchrotron Science

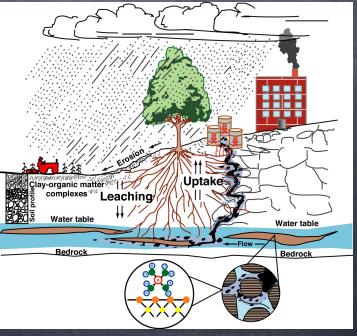








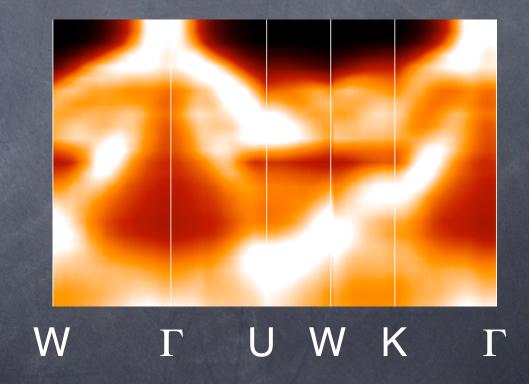




Electronic Structure

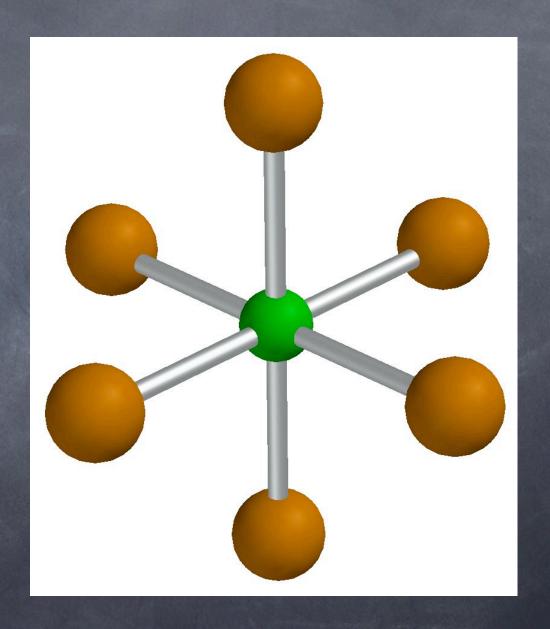
- Electron Dispersion
 - Mechanical Stability
 - Corrosion Resistance
 - Chemical Reactivity
 - Electrical Conductivity
 - Thermal Conductivity
 - Magnetism
 - Wolfgang Eberhardt

H-Si(111) 1x1

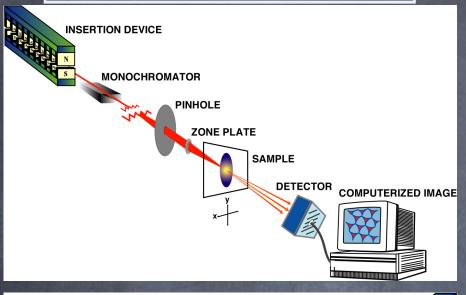


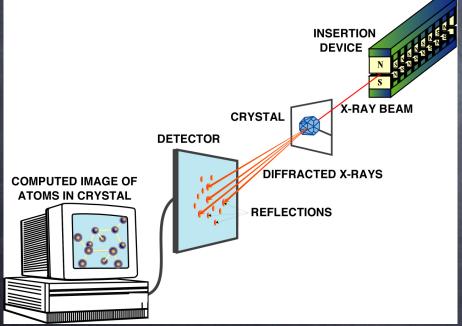
Geometric Structure

- Atom Positions
- Atom Types
- Bond Lengths
- Geometry



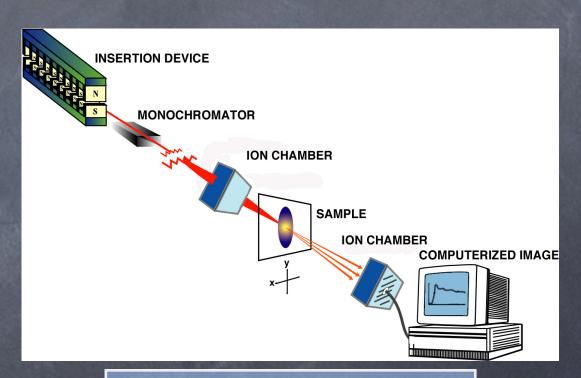
X-ray Microfocus





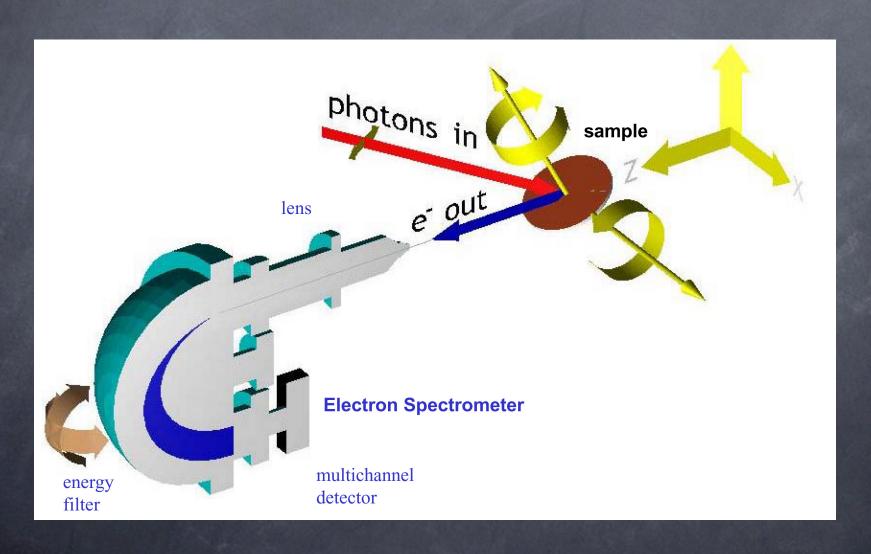
X-ray Scattering

MR-CAT Materials Research



X-ray Absorption

Photoemission Measurement

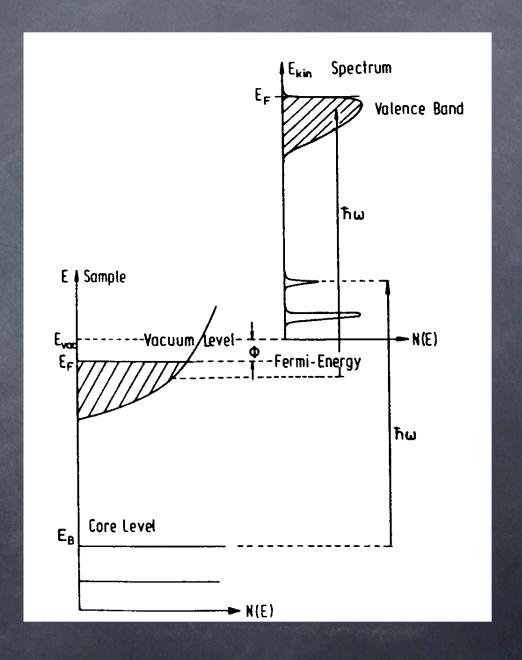


X-ray Techniques

- Photoelectric
 Effect
 - Photon In
 - Electron Out
- Every Atom Has
 Orbitals With
 Different Binding
 Energies

PHOTOEMISSION

- Photoelectric Effect
 - Photon In
 - Electron Out
 - \odot KE = $hv BE \phi$
- Probes Occupied Electronic States



Cross Section

How do we understand photoemission?

$$\sigma_{nl}(E) = \frac{4}{3}\pi^2 \alpha a_0^2 \left[N_{nl}(E - E_{nl}) \frac{1}{2l+1} \right] \left[l R_{E,l-1}^2 + (l+1) R_{E,l+1}^2 \right]$$

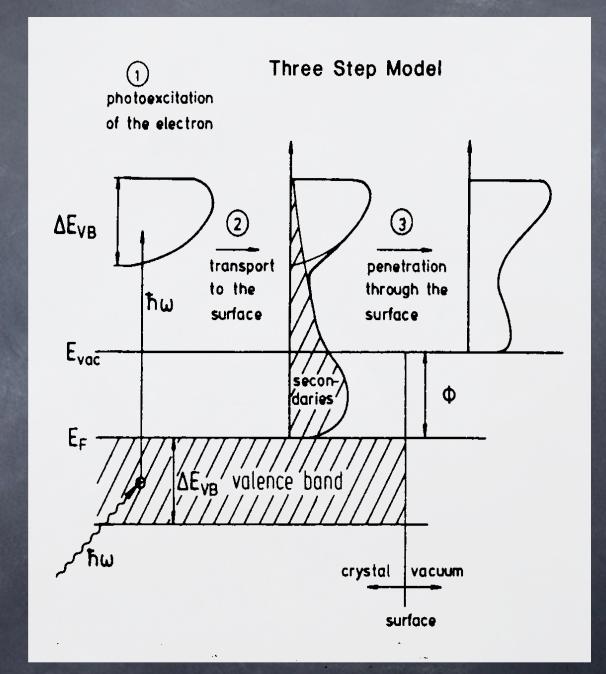
where α is the fine structure constant; a_0 is the Bohr Radius, N_{nl} is the number of electrons in the subshell, E_{nl} is the binding energy of the level, and E is the energy of the ejected electron.

electron.
$$R_{E, l \pm 1} = \int_{0}^{\infty} P_{nl}(r) r P_{E, l \pm 1}(r) dr$$

where $P_{nl}(r)$ is the radial part of the wavefunction.

Theory

- Three Step Model
- W. Spicer
 - Photoexcitation
 - Transition Matrix Element
 - Transport to Surface
 - KE > Vacuum Level but elocated inside crystal
 - Scattering
 - Escape from Surface
 - Refraction at Barrier



EXAFS Theory

Single Scattering Approximation

$$TP \propto rac{2 \pi}{\hbar} \left| \left\langle \psi_f \right| \varepsilon \cdot r \left| \psi_i \right\rangle \right|^2 \delta \left(E_F - E_i - \hbar \omega \right)$$

but ψ_f is complicated.

$$\psi_f = \psi_0 + \sum_j \psi_j$$

$$\psi_0 \sim \left(\frac{e^{ikr}}{kr}\right)$$
 and $\psi_j \sim \left(\frac{e^{ik|\vec{r} - \vec{r}_j|}}{k|\vec{r} - \vec{r}_j|}\right)$

Define a function,

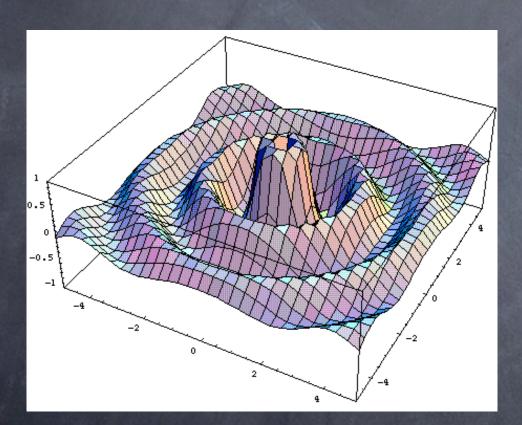
$$\chi = \sum_{j} \frac{\psi_{0}^{*} \psi_{j} + \psi_{j}^{*} \psi_{0}}{\psi_{0}^{*} \psi_{0}}$$

EXAFS Equation

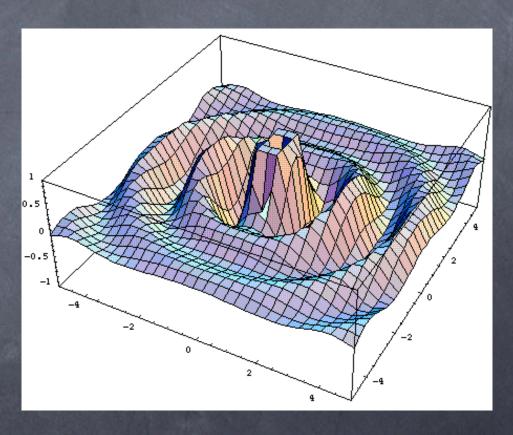
$$\chi(k) = \sum_{j} \frac{N_{j} f_{j}(k)}{r_{j}^{2}} e^{\frac{-2r_{j}}{\lambda(k)}} e^{-2k^{2}\sigma_{j}^{2}} \sin\left(2kr_{j} + 2\delta_{e} + \delta_{j}\right)$$

EXAFS

No Scatterers

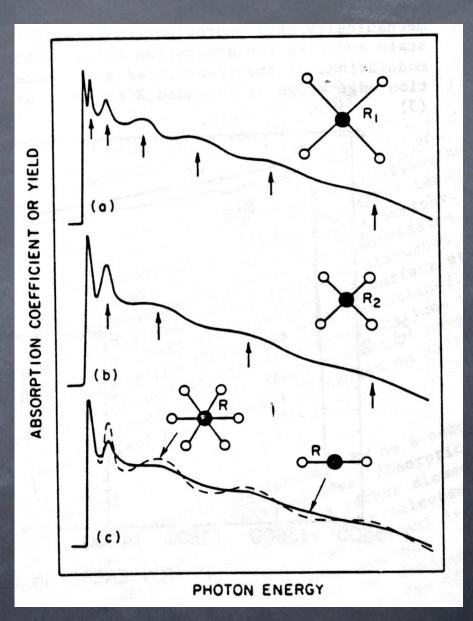


Scatterers



Fine Structure

- Fine Structure
 - @ R1>R2
 - Higher FrequencyOscillations
 - N1>N2 at fixed R
 - Higher Amplitude Oscillations
 - Same Frequency



J. Stohr Nexafs Spectroscopy

Ag/X Clusters X=Pt/Pd

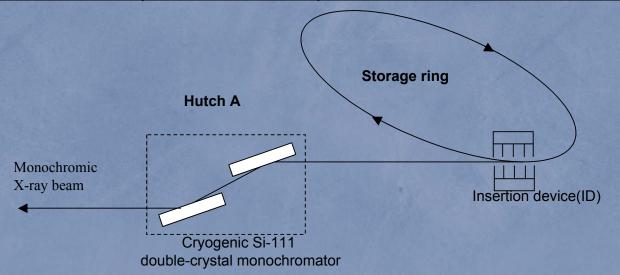
- Aqueous Metal Salt Solution
- Mole Ratios 20/80 to 80/20
- Radical Scavanger 2-propanol
- Poly(vinyl alcohol)
- Gamma Irradiation at UMR Reactor Pool
 - 36-48 Hours 3-3.5kGy
- Radiolysis

Radiolysis

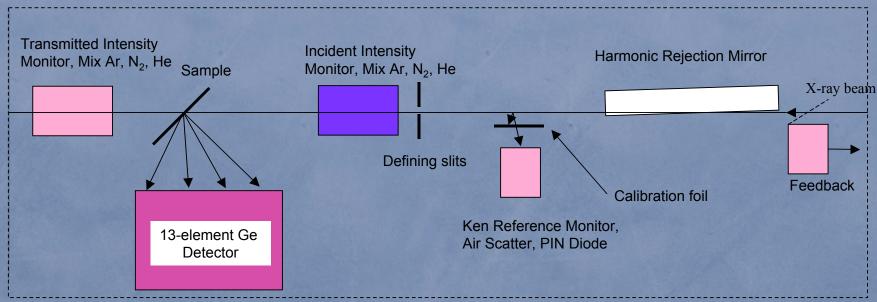
$$H_2O \stackrel{\gamma \text{ - radiation}}{\longrightarrow} e_{aq}^-, H_3O^+, H^+, OH^+, H_2O_2$$
 $e_{aq}^- + M^{m+} \longrightarrow M^{(m-1)+}$
 $e_{aq}^- + M^+ \longrightarrow M^0$
 $n M_0^0 \longrightarrow (n-2) M_0^0 + M_2^0 \longrightarrow ... M_n^0$

XAS Experimental

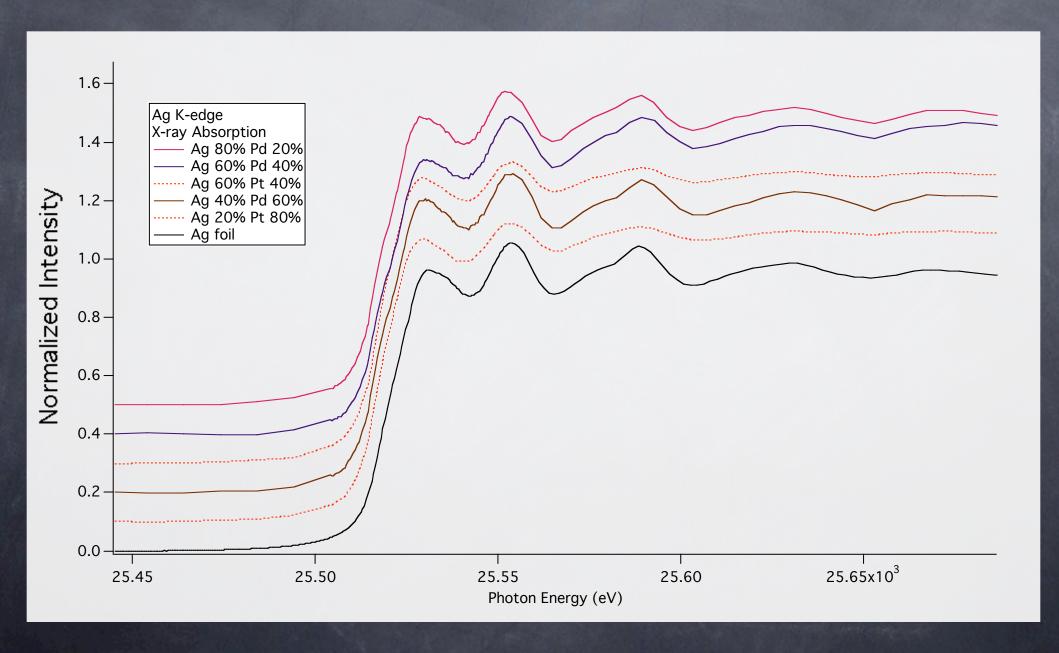
MRCAT Beamline, Sector 10ID-B, Advanced Photon Source



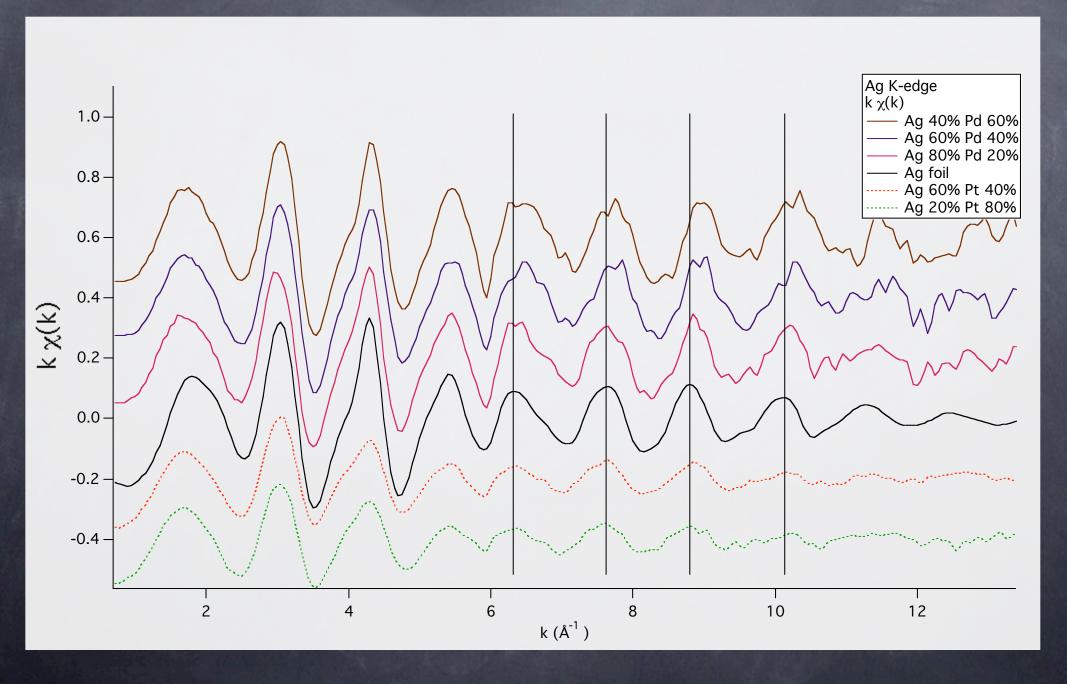
Experimental Hutch B



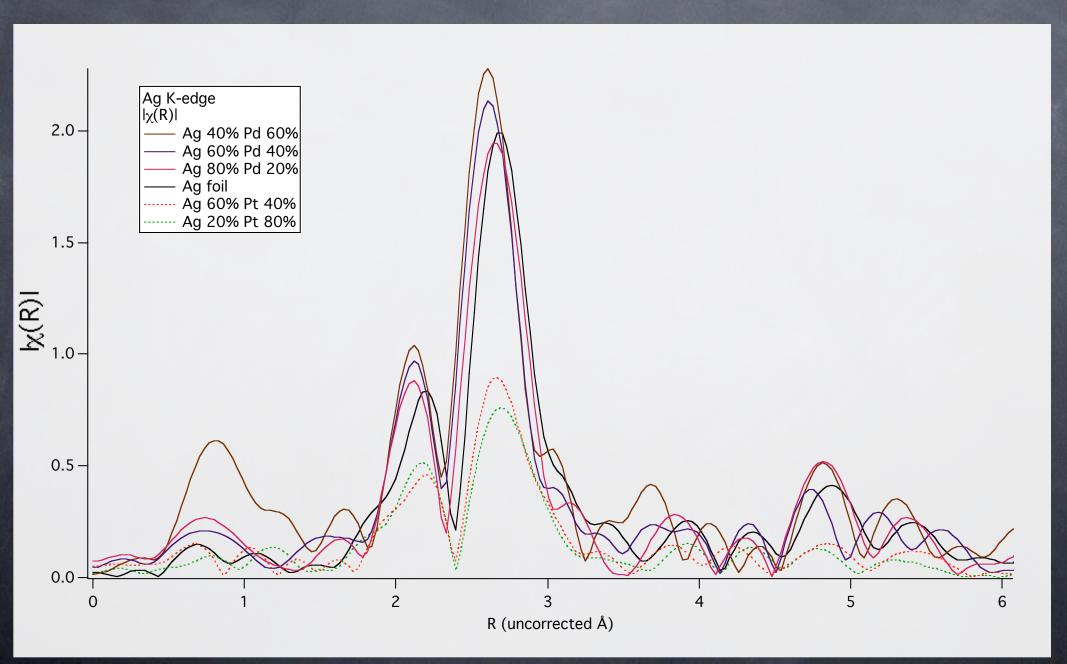
Ag K-edge



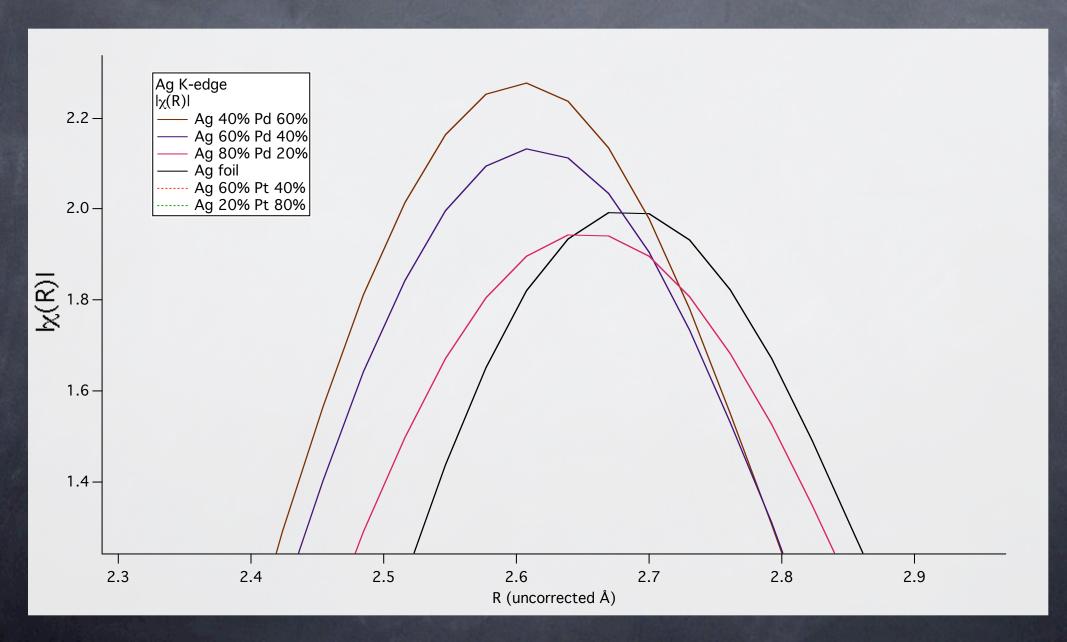
Ag K-edge x(k)



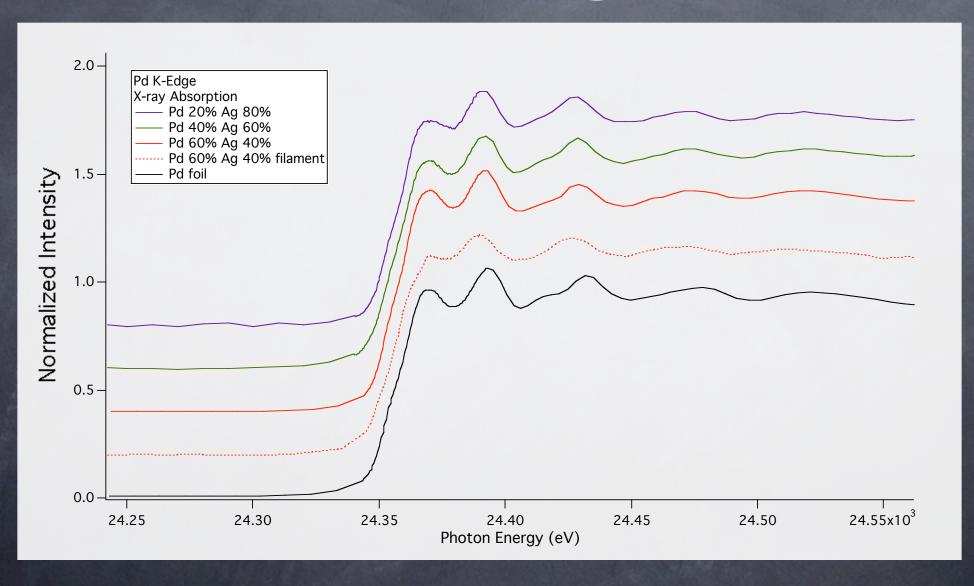
Ag K-edge x(r)



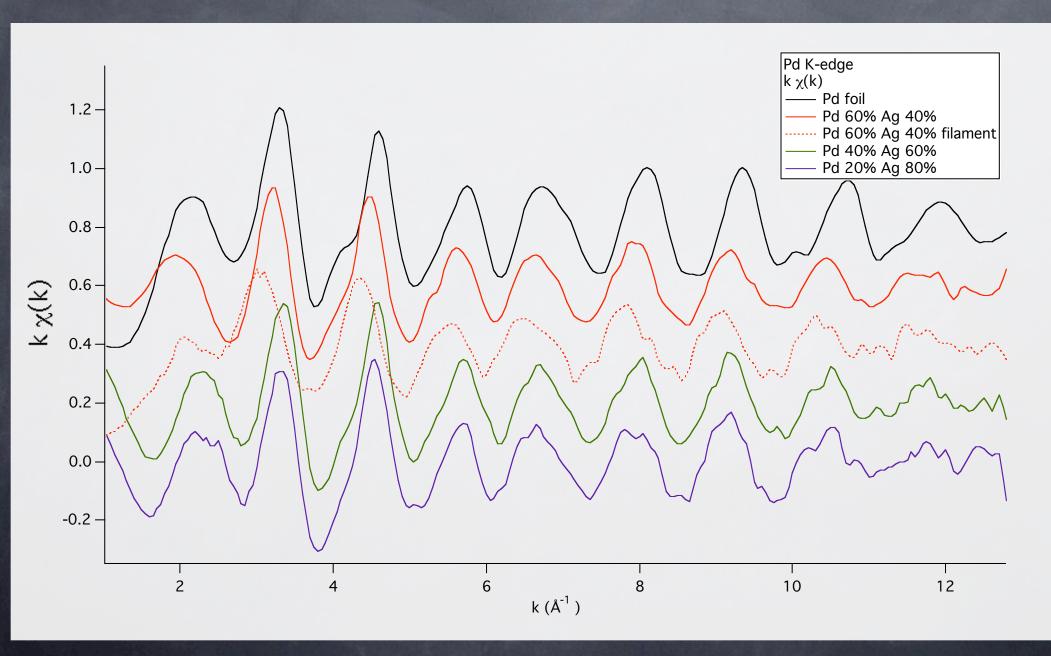
Ag K-edge x(r)



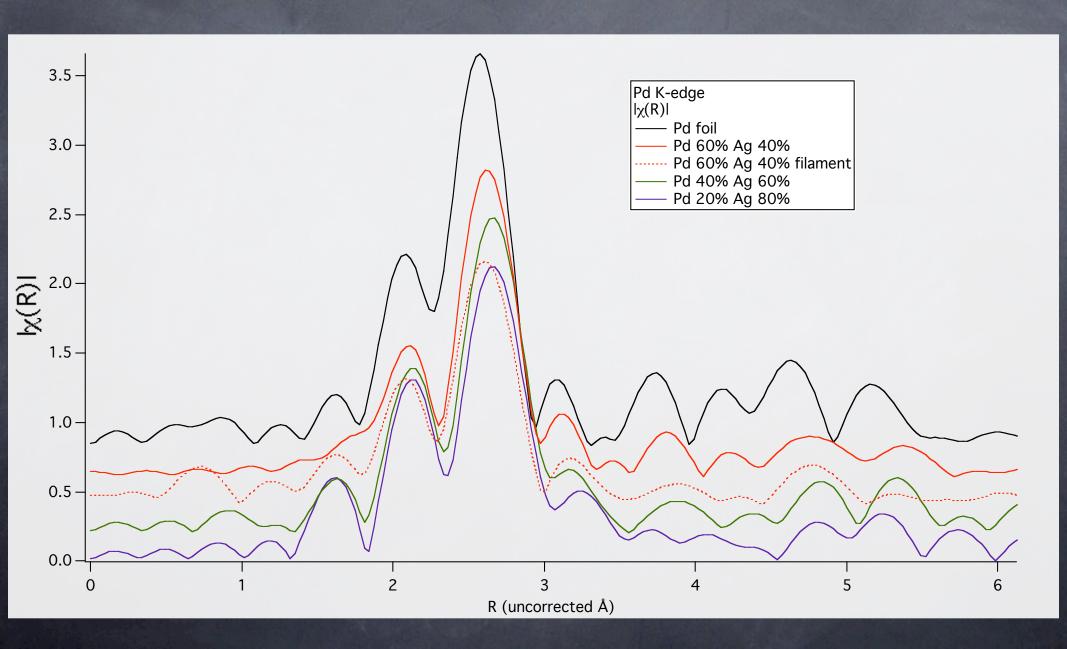
Pd K-edge



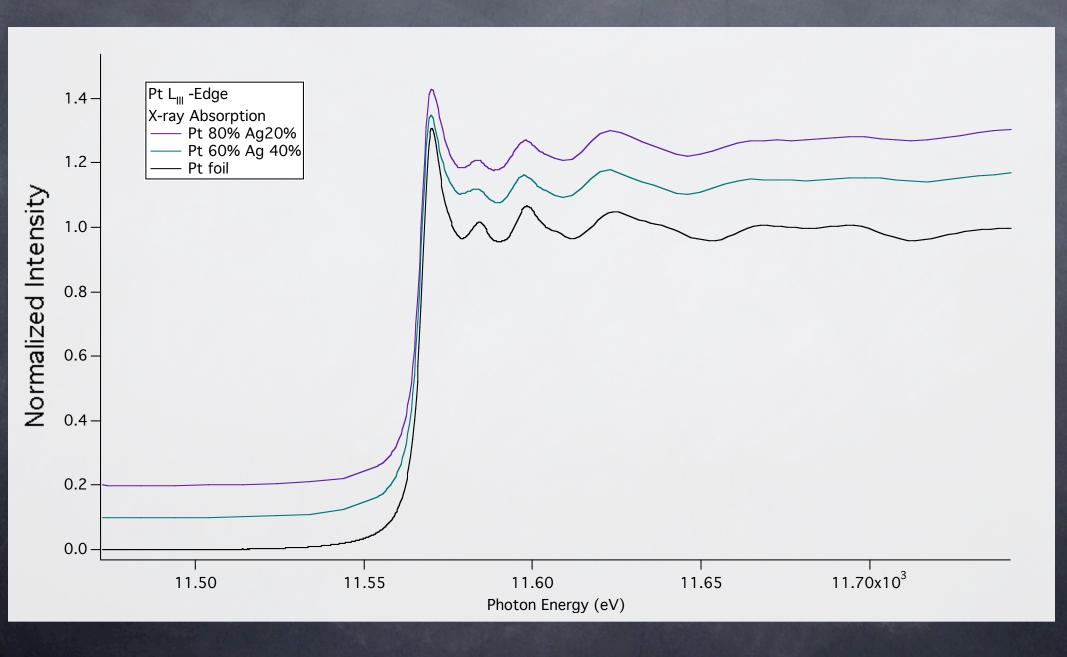
Pd K-edge x(k)



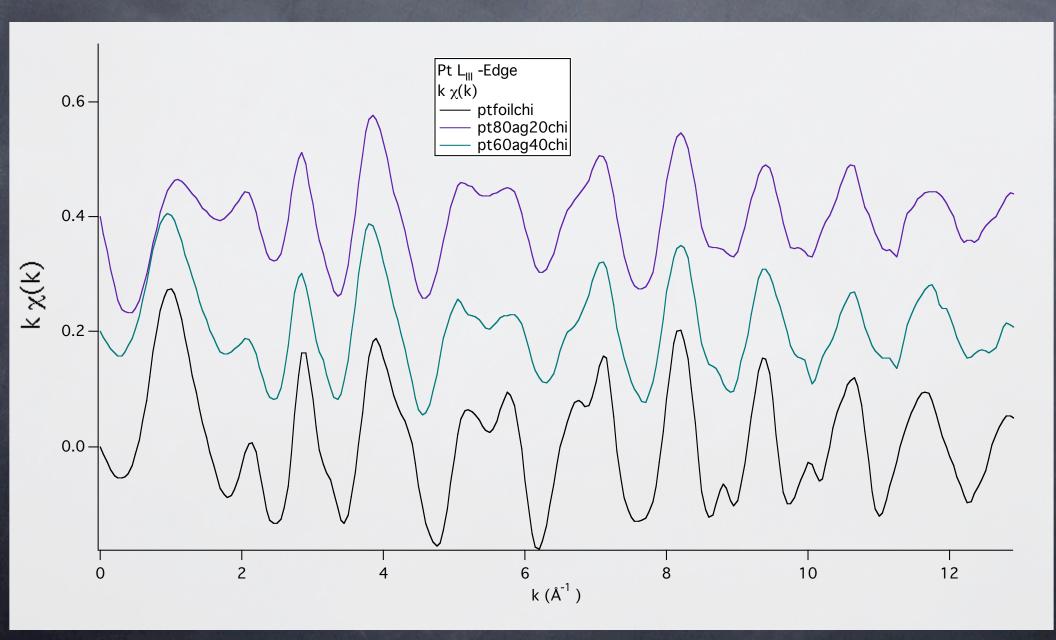
Pd K-edge x(R)



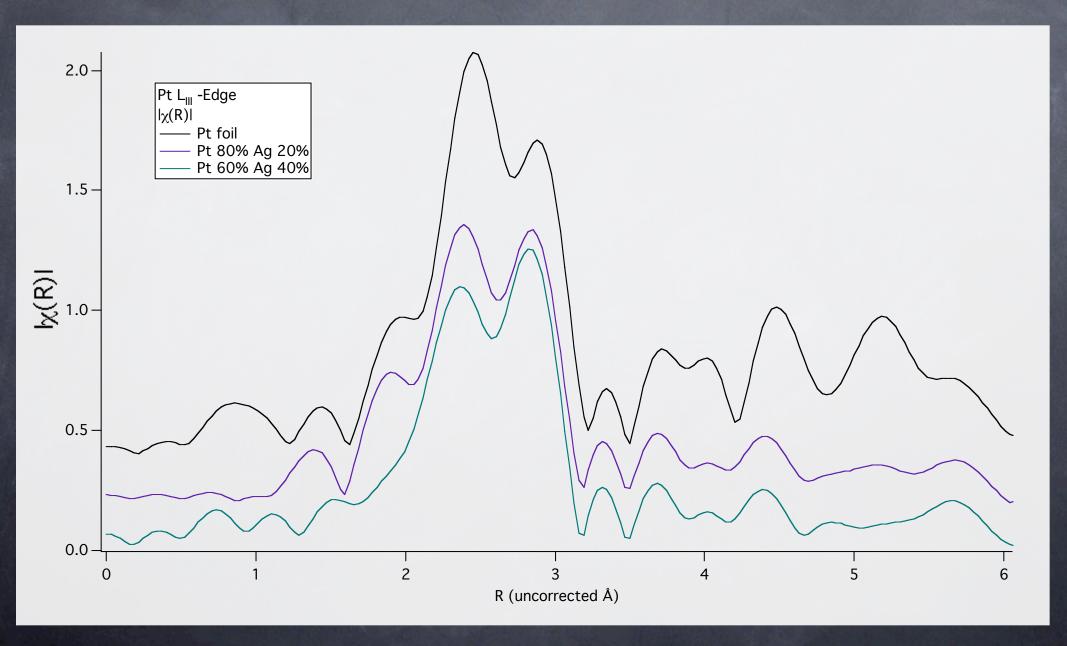
Pt K-edge



Pt K-edge x(k)



Pd K-edge x(R)



Qualitative Trends

- Ag Edge
 - AgPd Shorter Bond Length Trend
 - AgPt No Strong Trend
- Pd Edge
 - AgPd Longer Bond Length Trend
- Pt Edge
 - AgPt No Strong Trend

Cluster Feff Calculations

- Feff 8.2 is a program designed to calculate the X-ray absorption spectrum of a system from 1st principles.
- It uses the Local Density Approximation method of Density Functional Theory to calculate self-consistent potentials that it uses to model electron scattering in a material.

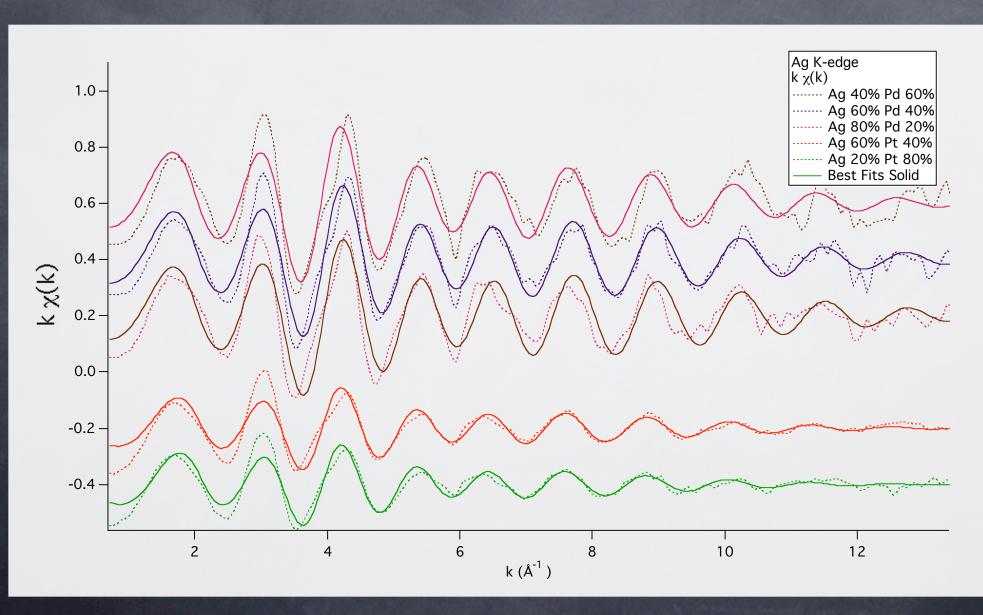
Feff Calculations

- We must make assumptions about our system in order to model it with Feff.
- In the case of the AgX Clusters, we made the assumption that we could model the clusters by starting with Pd, Pt, and Ag crystals.
- We substituted the proposed alloy material into a perfect crystal and calculated the expected scattering paths.

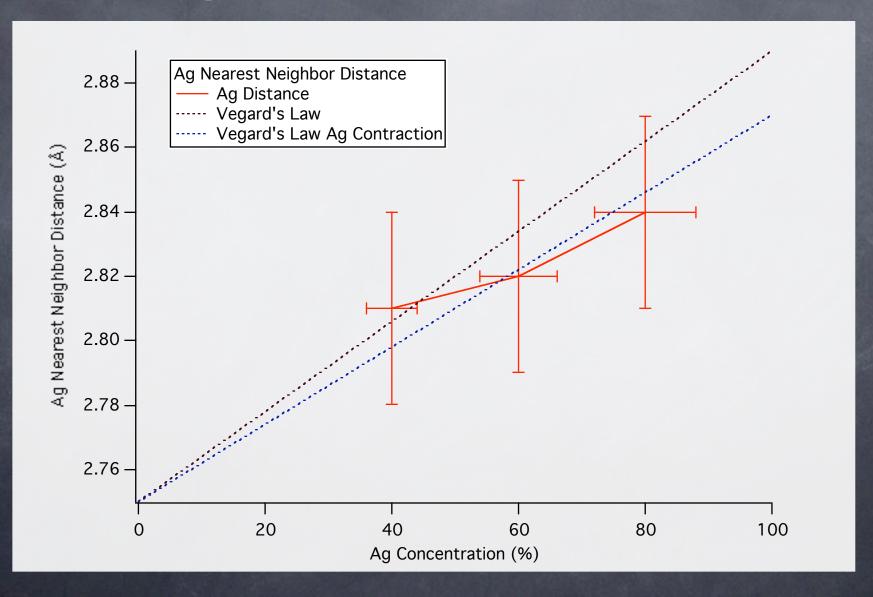
Feff Fitting of Expt DATA

- We fit the experimental data to determine bond lengths from both directions to determine and approximate error in our measurements.
- Typically, the error that this directional fitting introduced was 0.03Å.

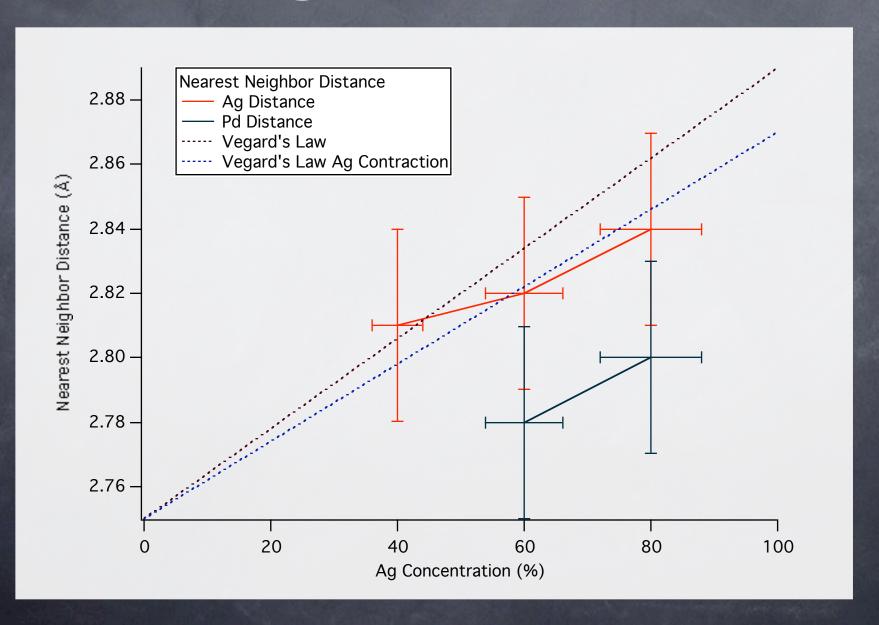
Fitting Ag



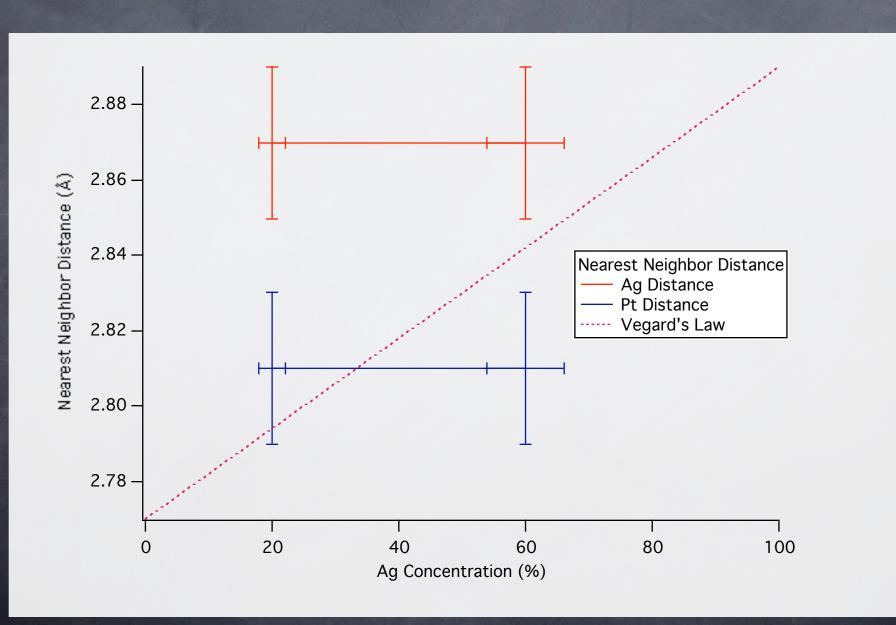
AgPd Fit Results



PdAg Fit Results



AgPt



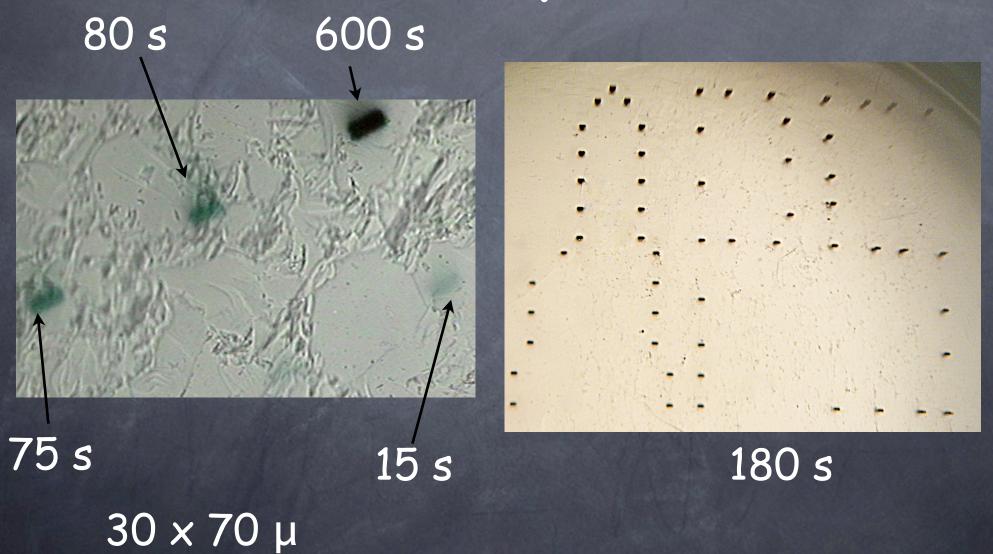
Dielectric Devices

- Create nanowires in aerogels.
- Aerogels are non-conductive.
- Aerogels are great thermal insulators.
- Aerogels mainly SiO₂.

Tailor Properties

- Soak aerogel with AgNO₃ in 2-propanol.
- Irradiate with highly-collimated X-ray beam.
- Trradiations as low as 30 s cause the formation of conductive arrays of Ag nanoclusters.

Example

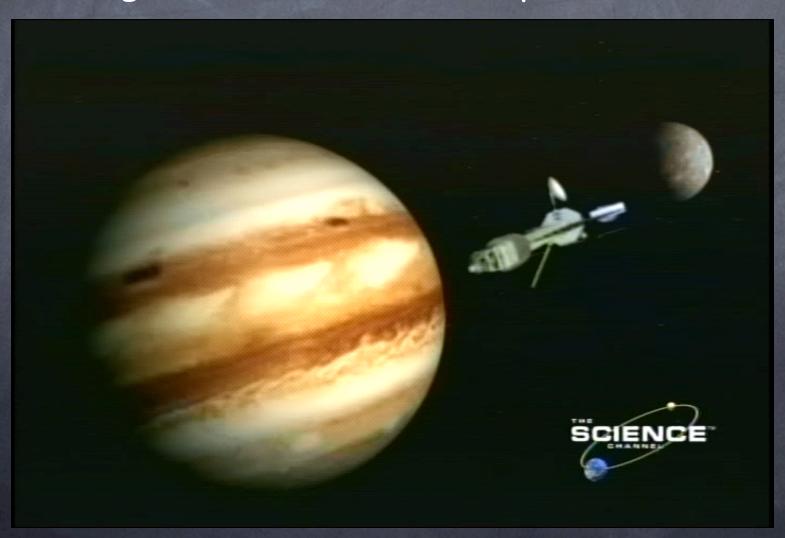


Conclusions

- Rule out alloying in AgPt system.
- Very Confident of alloying in AgPd system.
- Possible local segregation of Pd in AgPd system reducing average near-neighbor length.
- Create wires of nanoparticles in dielectric materials to tailor properties.

Radiation Damage

Many reasons to be interested in radiation damage. One of the most important to me is:



Radiation Damage

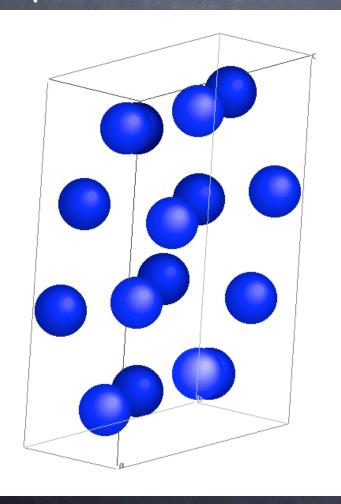
- Many reasons to be interested in radiation damage. One of the most important to me is:
 - Space Travel
- I will illustrate how the synchrotron techniques can be used to study radiation damage with Pu alloys and Spinels

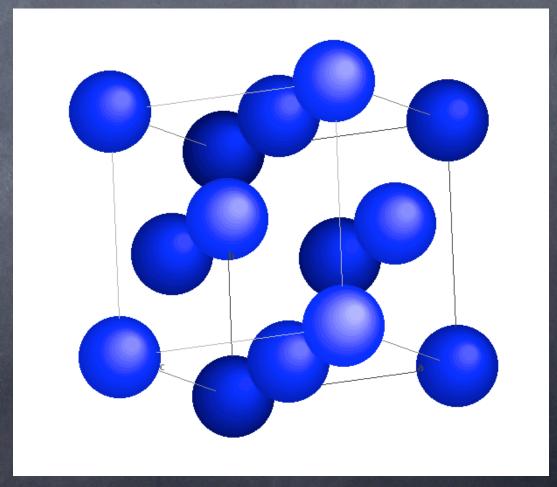
Pu CRYSTAL STRUCTURES

The Plutonium phase diagram is complex between 25 C and 600 C plutonium undergoes 5 phase transitions.

Alpha (monoclinic)

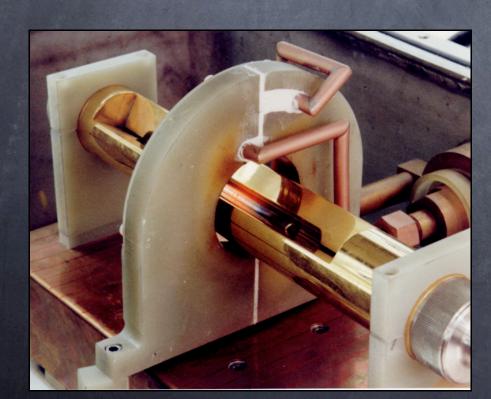
Delta (face-centered cubic)

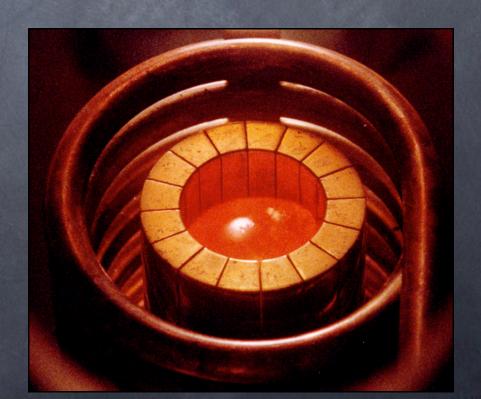




SAMPLE PREPARATION

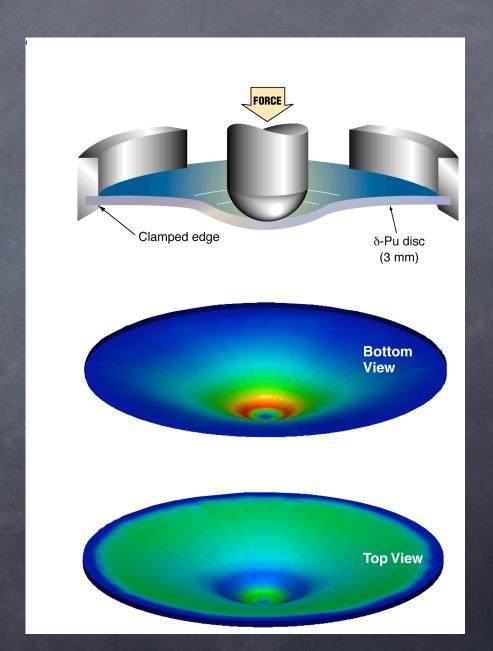
- Levitation Zone Refinement
 - 1.5 cm/min Zone Travel Rate
 - 800 °C Molten Zone (red glow)
- Levitation Distillation
 - 180 ppm Impurties





STRAIN ANNEALING

- Solid State Crystal Growth
 - Deform Metal (Strain)
 - Heat (Anneal)
- Grain Growth Predominates
 - Net Increase of Grain Size



OLANL

- Repeated Sputter-Anneal Cycles to Remove Dissolved O₂
- Samples Transferred to Vacuum Transfer Vessel

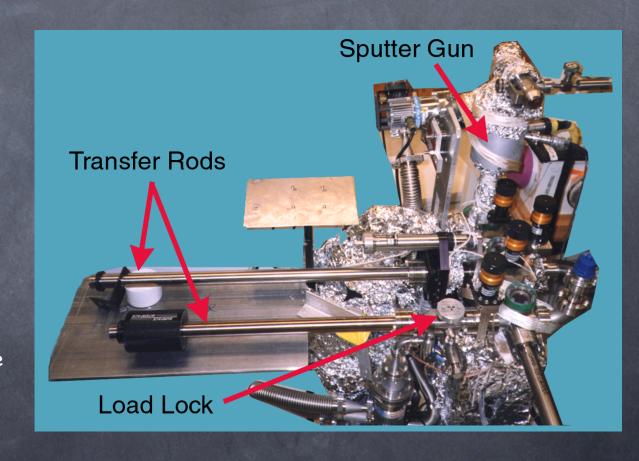
Shipping

Samples Shipped in Vacuum Transfer Vessel at 10⁻⁸ Torr

ALS

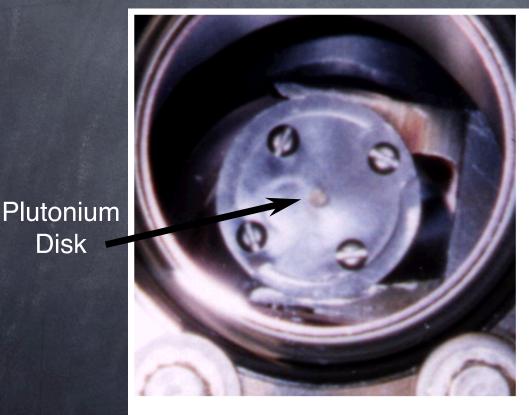
- Final Cleaning Done in Sample Handling and Integrated Transfer System for Pu Intense Light Experiments
 - Sputter 5 kV Ar ions
 - Anneal 75 °C

SURFACE PREPARATION



SPUTTER CLEANING

- Sputtering Removes Surface Contamination
- Annealing Removes Sputter Induced Defects



Disk

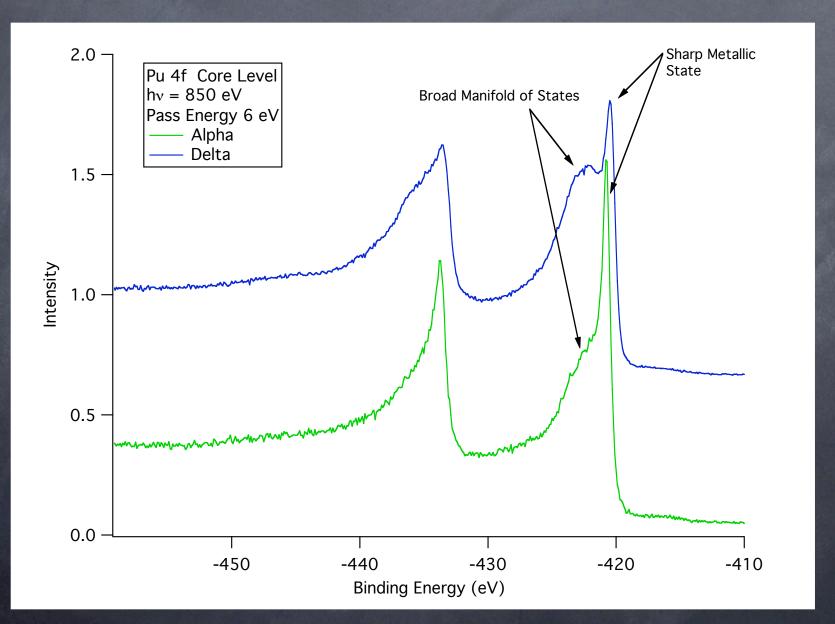
Plutonium Disk

Before Sputter

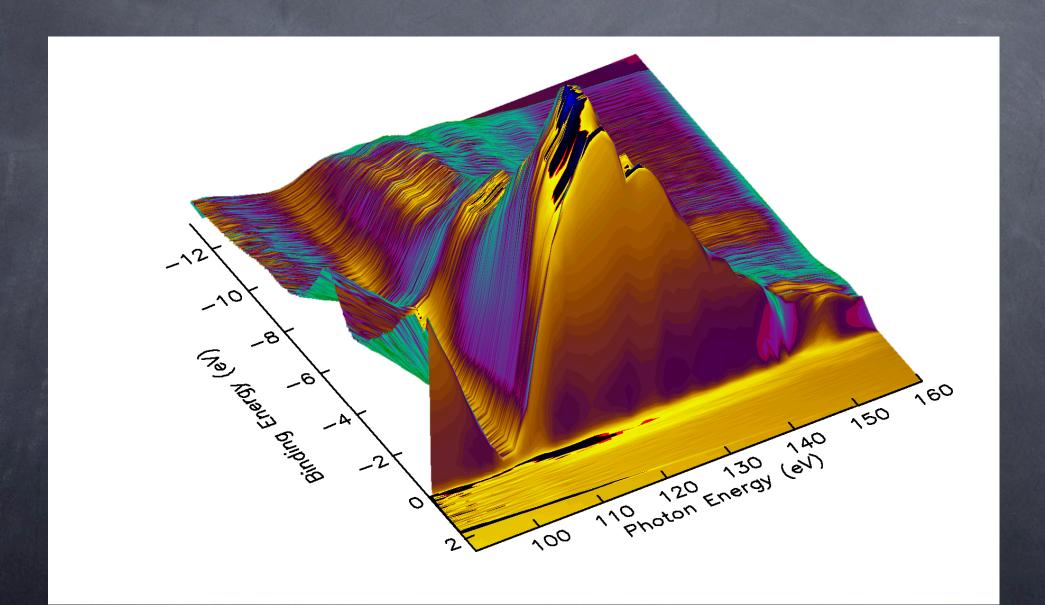
After Sputter

Pu CORE LEVEL PES

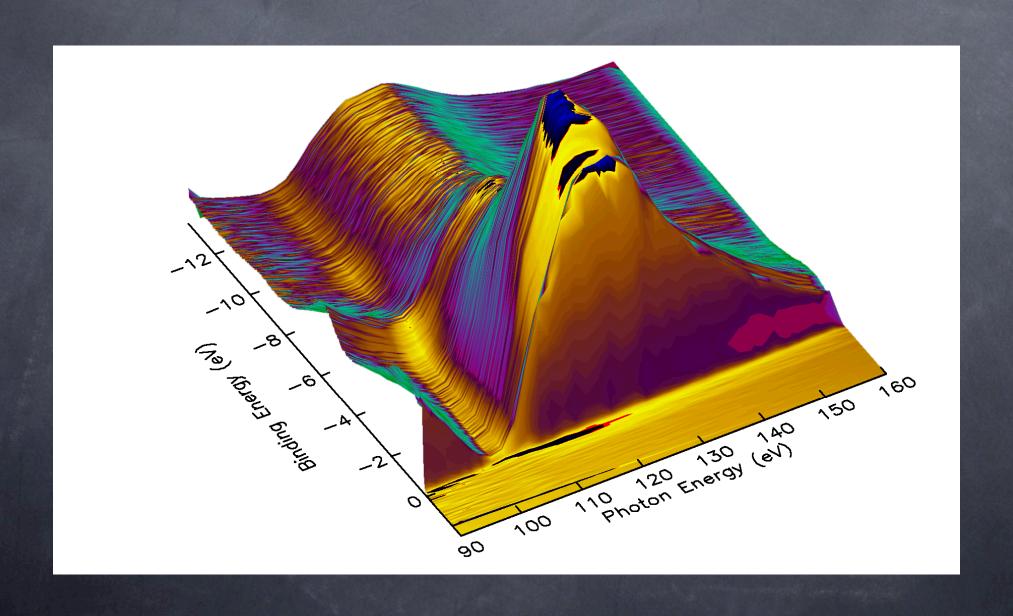
4f Core Level Photoemission



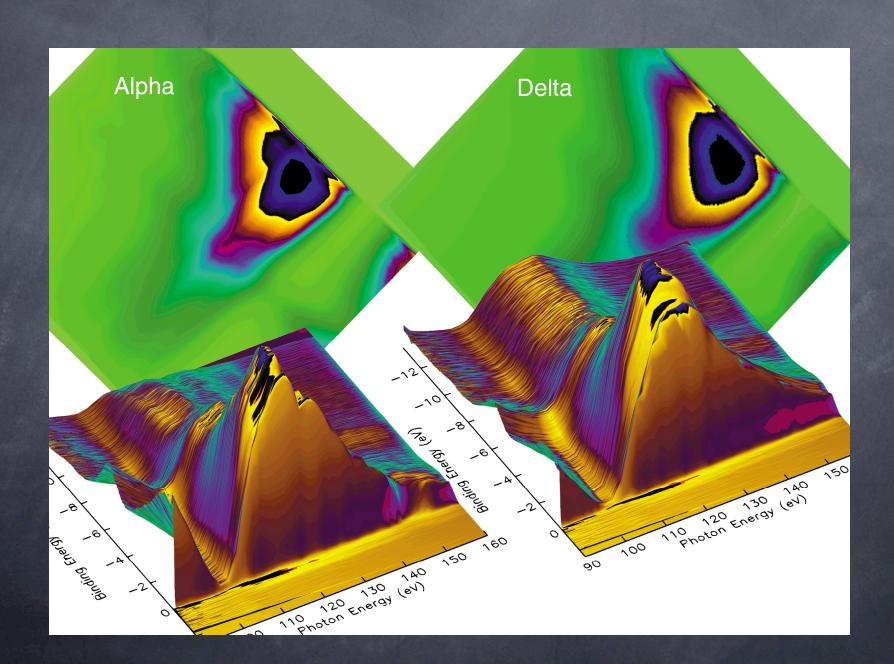
ALPHA RESPES



DELTA RESPES

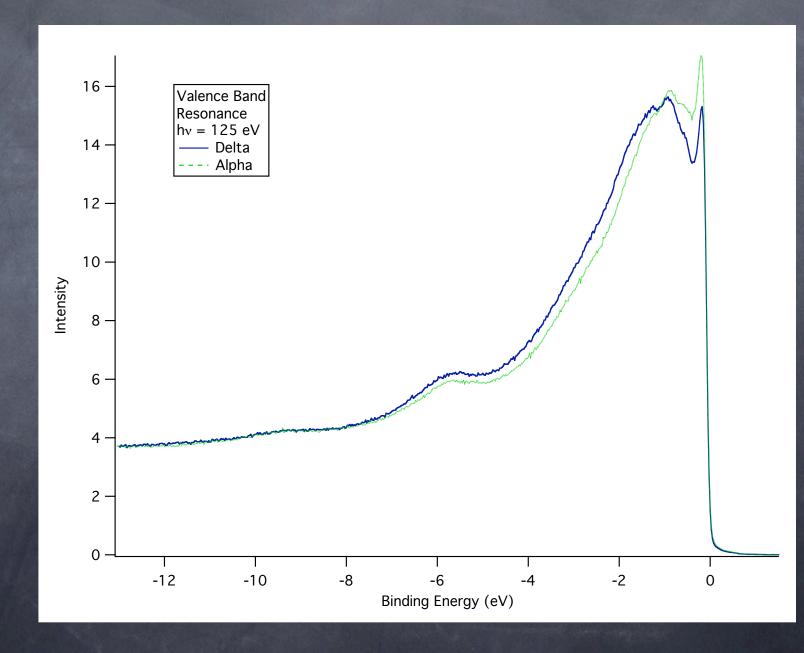


RESPES



VALENCE BAND

- Density of States
 - Alpha more density near E_f
 - Delta more density at higher binding energy away from E_f
- Consistent with localization of felectrons in Delta



Band Theory

Band Structure

Density Functional
Theory

$$\circ$$
 n(r) = $|\Psi(R)|^2$

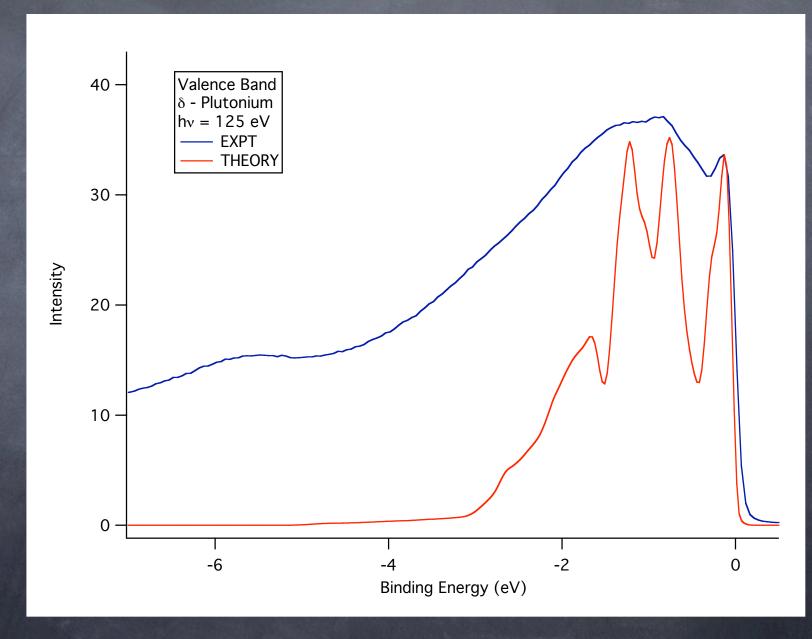
- LDA assume slowly varying n(r)
- Correlated Electron Effects

$$\bullet$$
 $E_{tot} = E_{LDA} [n_{itin} + n_{loc}] + \Delta E_{corr} [n_{loc}]$

$$o n_{loc} = 4$$

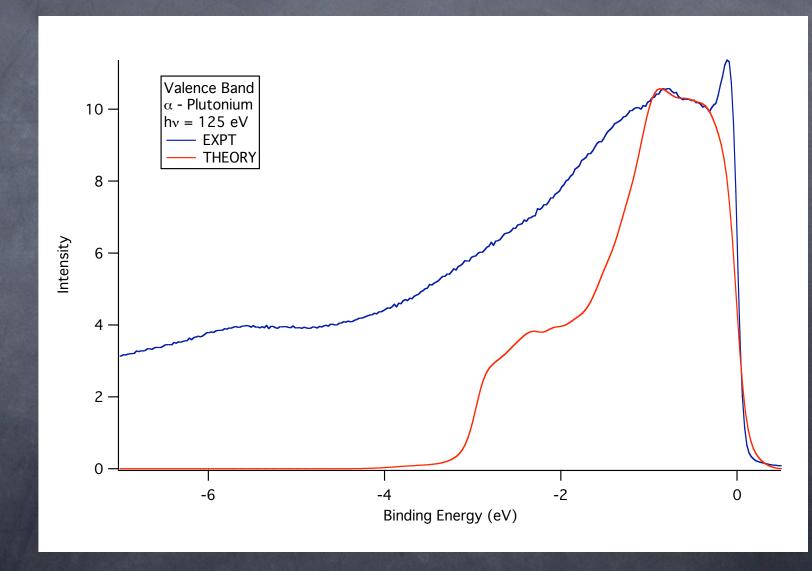
DELTA THEORY

- Density of States
 - 4 localized 5f electrons
- Good Agreement
 - Theory Missing One Peak at ∼0.5 eV
 - Photoemission
 Matrix
 Elements NOT
 Accounted for
 in Calculation



ALPHA THEORY

- Density of States
 - All 5f electrons itinerant
- Good Agreement
 - Theory Missing One Peak at E_f
 - Photoemission
 Matrix
 Elements NOT
 Accounted for
 in Calculation



ResPes Theory

- Resonant
 Photoemission
 - Atomic Calculation
 - Resonant Channel
 - Direct Channel
 - Interference between the two channels gives rise to resonant photoemission

- $<5d^{10}5f^{5}|r|5d^{9}5f^{6}> -> <5d^{9}5f^{6}|e^{2}/r|5d^{10}5f^{4} + e->$
- $<5d^{10}5f^{5}|r|5d^{10}5f^{4} + e->$

Fano Paraameter (q)

 $q \sim (5d^{10}5f^5|r|5d^95f^6) / (5d^{10}5f^5|r|5d^{10}5f^4 + e)$

Pu RESPES

16 -

14 -

12 -

10

8 -

Fano Lineshapes

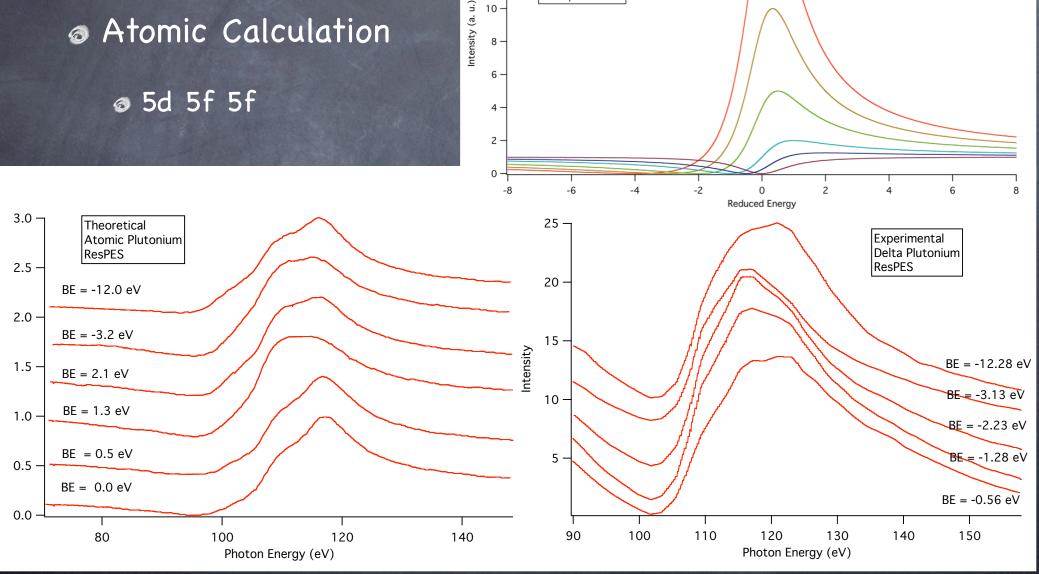
Dependence Upon Fano Parameter (q)

> q = 0.5q = 0

Resonant Photoemission

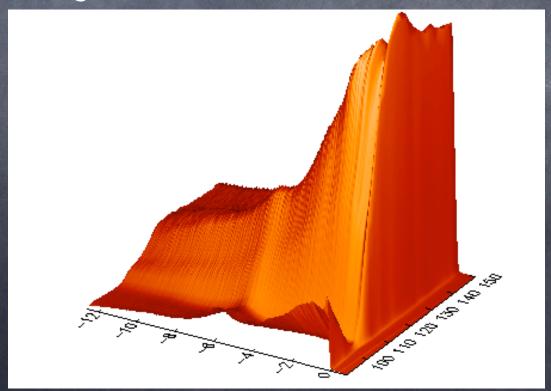
Intensity

Atomic Calculation



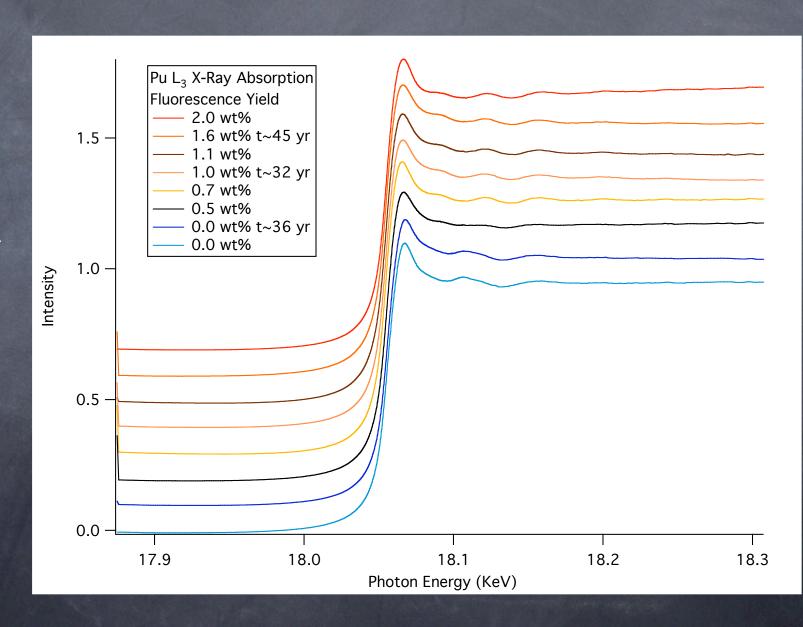
Radiation Damage???

- Science Based Stockpile Stewardship
 - 38 year-old Plutonium
 - \odot Lineshape similar to δ -Pu
 - High Energy Oscillatory Structure similar to α-Pu

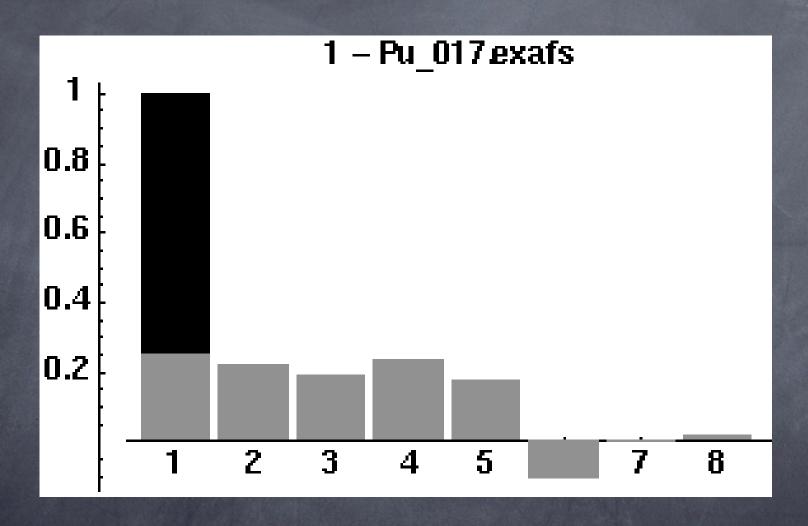


Pu L₃ Absorption Edge

- F-Yield
 - Bulk
 Measurement
 - Self-Absorptiom
- GalliumConcentration
- Sample Age

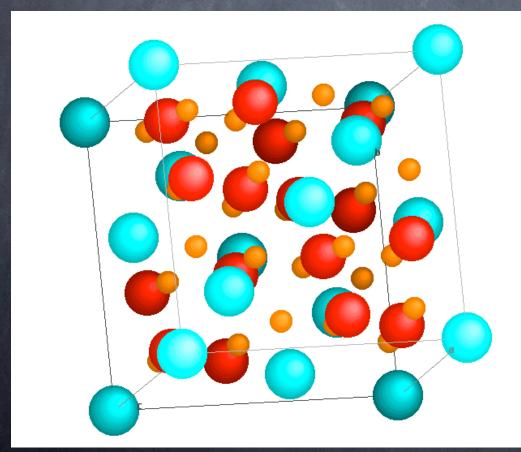


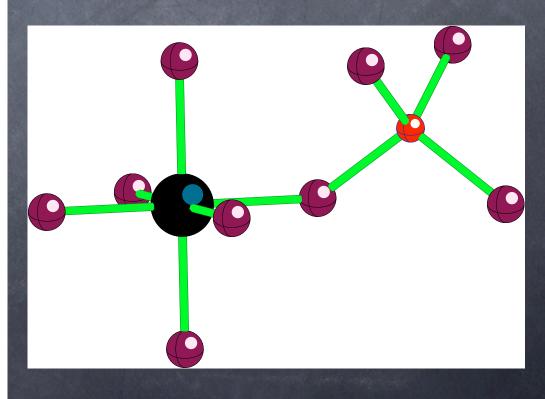
UNIQUENESS TESTING



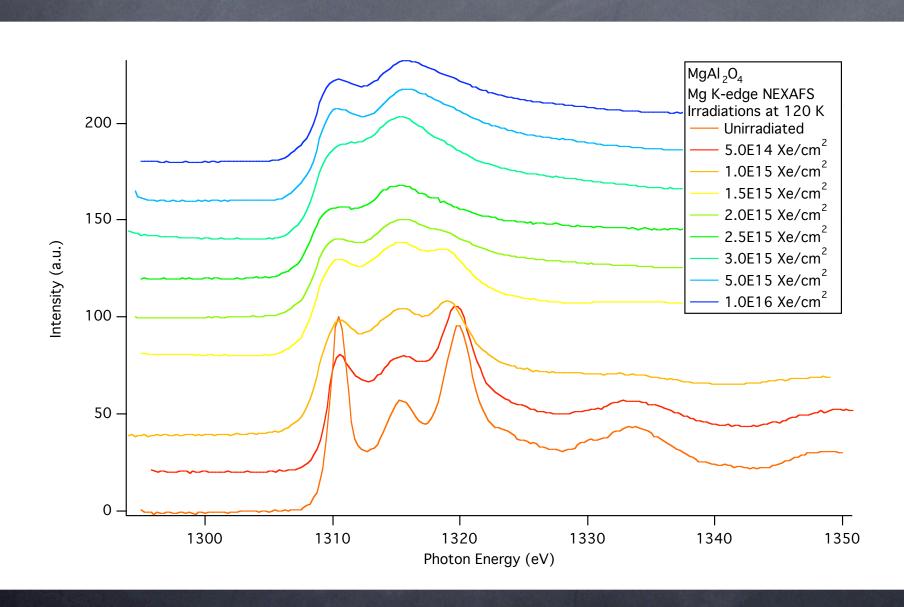
Ø 0.5 wt% Ga unusual

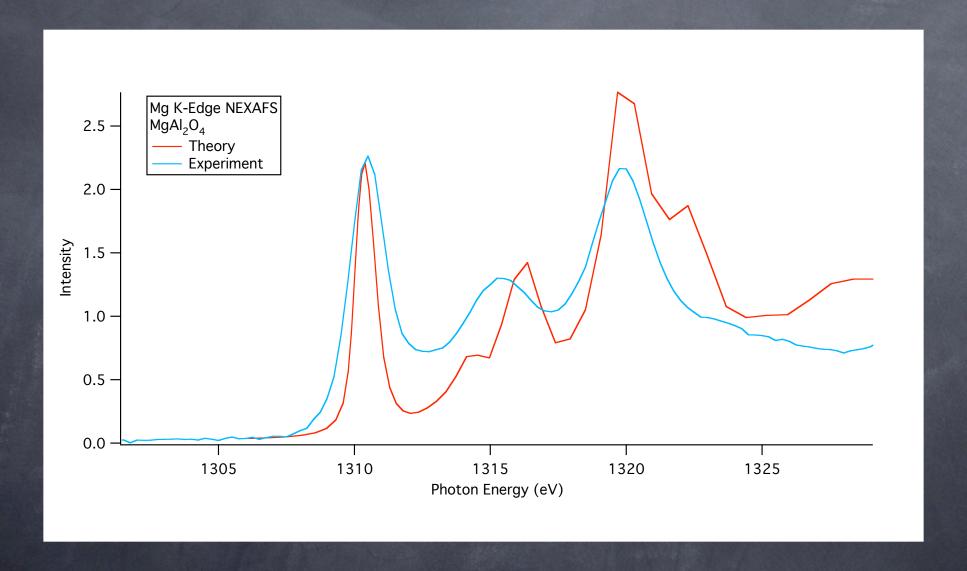
- MgAl₂O₄
 - Al octahedral
 - Mg tetrahedral





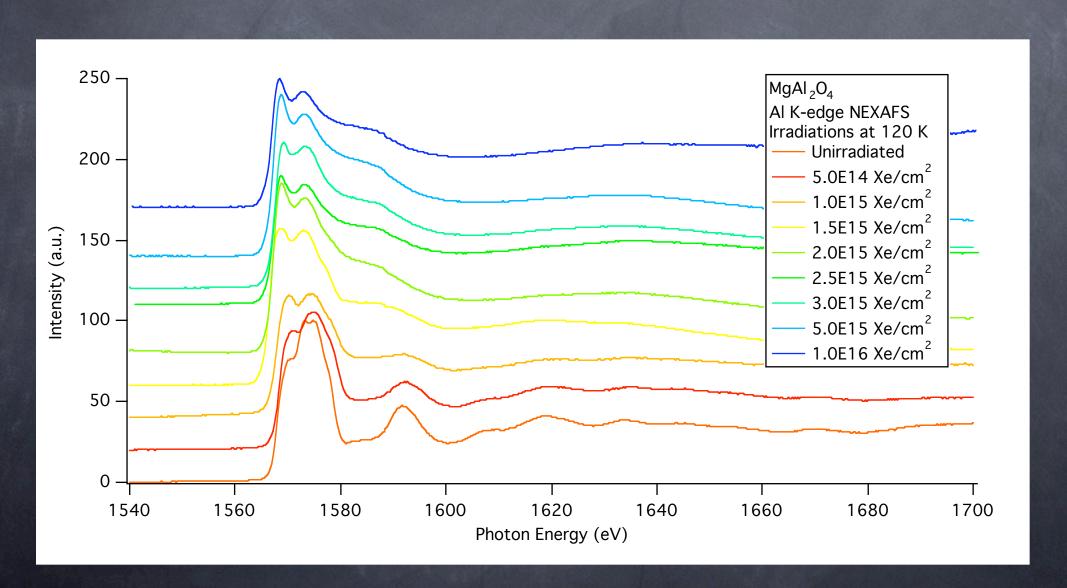
Mg K-edge NEXAFS



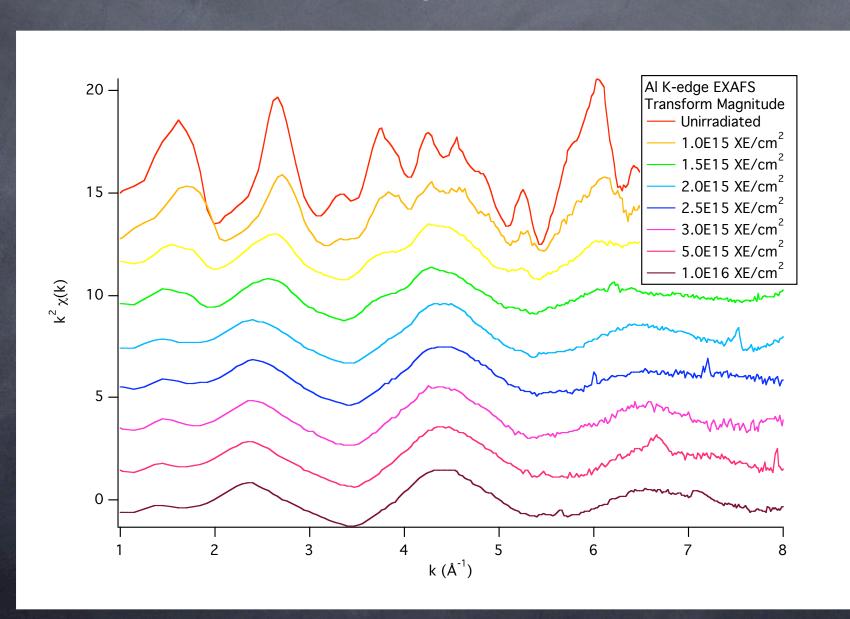


First Understand Starting Material

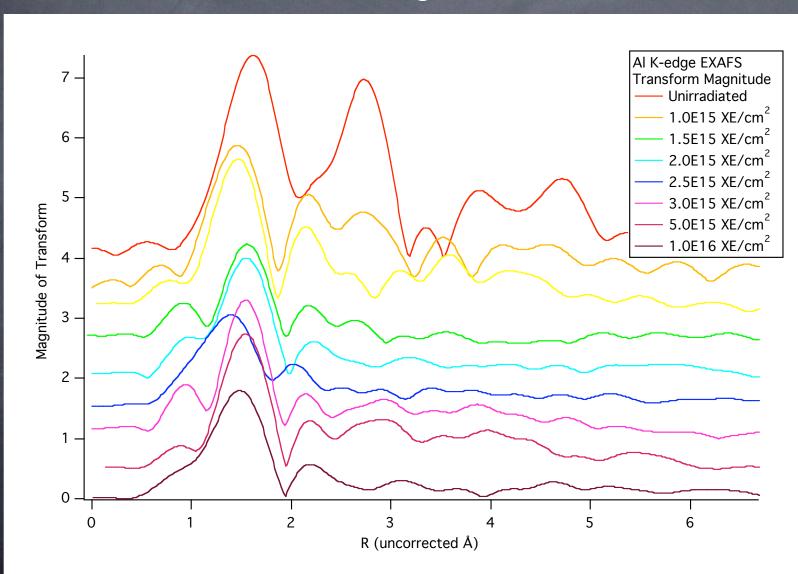
Al K-edge XAS



Al K-edge XAFS



Al K-edge XAFS



X-ray Absorption Good Probe of Radiation Damage

CdTe Solar Cells

- There are some people that just don't favor Nuclear Power
- Try to understand the mechanisms that limit efficiency in Solar Cells

CdTe Solar Cells

CdTe based Cell

EXAFS samples

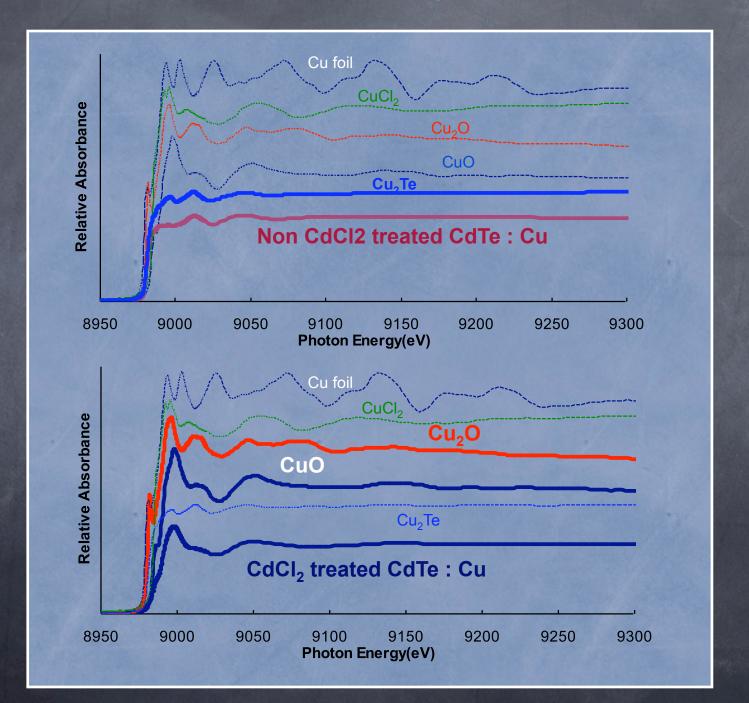
200Å Au
40Å Cu
2μm CdTe
1mm fused silica

Procedure: $2\mu m$ CdTe film on Qtz. CdCl₂ treatment in Air 40~200Å Cu 200°C Diffusion in N₂ for 45 min.

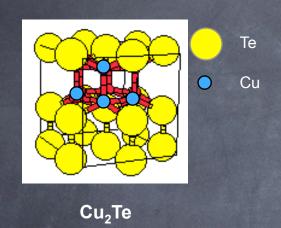
HCl etching to remove elemental copper left on surface

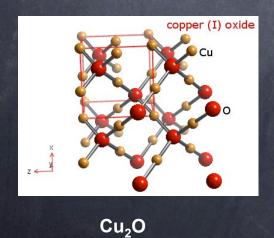
optional

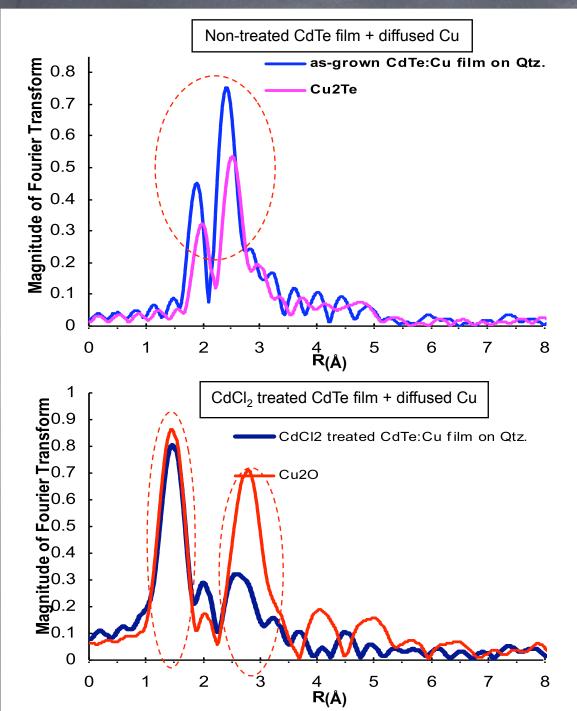
XAFS

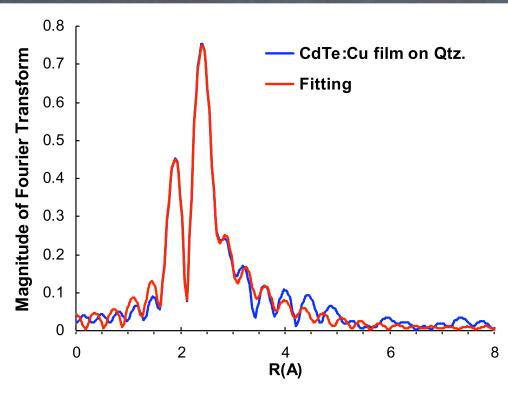


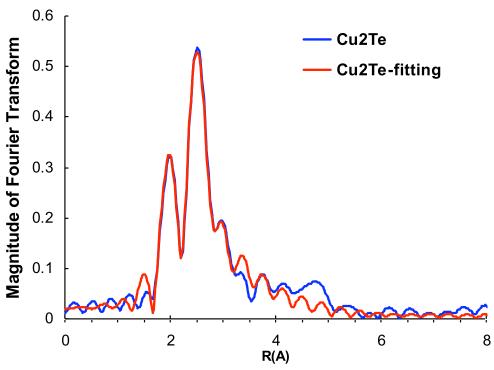
XAFS











XAFS

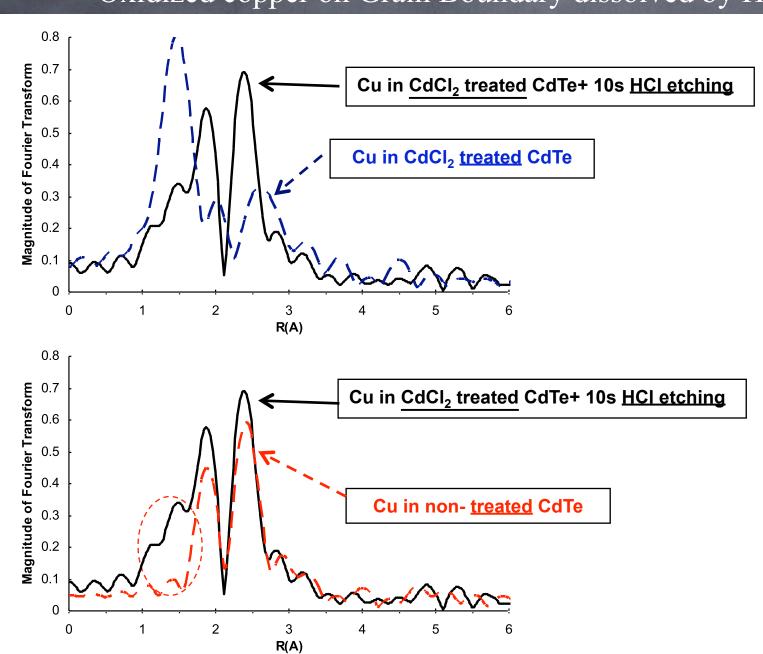
FEFF theoretical fitting to $\chi(R)$

As-grown CdTe:Cu film on Qtz.					
bond scattering	N	dN(+/-)	R(Å)	σ²(Å)	ΔE _o
Cu->Cu->Cu	1.53	0.39	2.22	0.010	3.69
Cu->Cu->Cu		0.37	2.45	0.005	
Cu->Te->Cu	3.78	0.96	2.56	0.024	
Cu ₂ Te					
Cu->Cu->Cu Cu->Cu->Cu Cu->Te->Cu	0.62 2.35 3.44	0.16 0.60 0.87	2.26 2.52 2.61	0.005 0.010 0.029	4.67

Cu_{2-x}Te forms in CdTe:Cu film

XAFS

Oxidized copper on Grain Boundary dissolved by HCl



Cu₂O lost after HCl etching

Cu2O Cu2Te CdTe

- @ Cu₂O
 - Band Gap ~ 2.0 eV
- @ Cu2Te
 - Band Gap ~ 1.5 eV
- CdTe
 - Band Gap ~ 1.5 eV
- Band Gap Mismatch Inhibits Recombination At Grain Boundary

Conclusions

- In polycrystalline CdTe film without Cl treatment, Cu resides predominantly in a Cu₂Te environment
- With Cl treatment, the chemical environment surrounding most of Cu atoms is similar to cuprous oxide Cu₂O
- © Cu₂O resides mainly as mono-layers along the grain boundary
- © Cu₂O may play a important role in grain boundary passivation
- Hot off the press, Cu₂O forming clusters during light soak

ACKNOWLEDGEMENTS

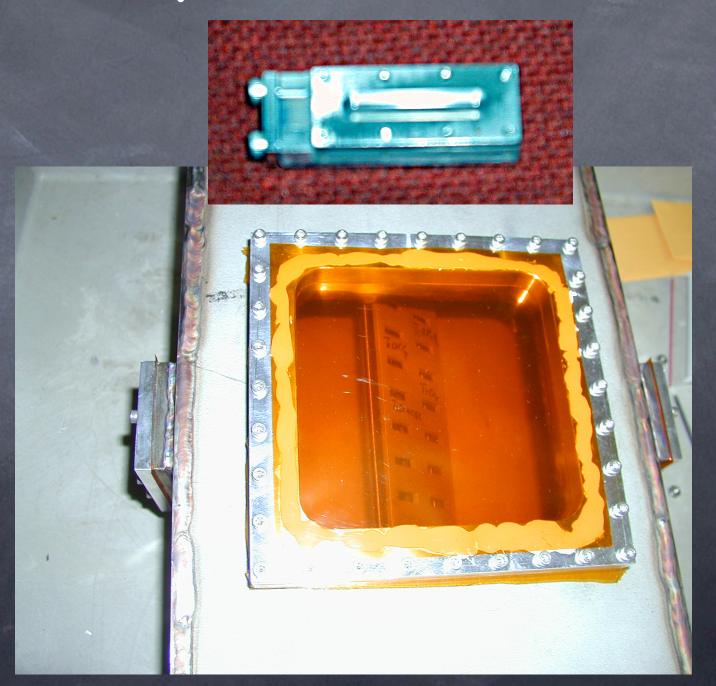
- The Advanced Light Source is supported by the Director, Office of Energy Research, Office of Basic Energy Sciences, Materials Sciences Division, of the U.S. Department of Energy under Contract No. DE-ACO3-76SF00098 at Lawrence Berkeley National Laboratory.
- The Stanford Synchrotron Radiation Laboratory is supported by the Department of Energy, Office of Basic Energy Science, Division of Chemical Sciences

ACKNOWLEDGEMENTS

- Los Alamos National Laboratory was operated by the University of California under Contract No. W-7405-ENG-36 with the U.S. Department of Energy.
- Use of the Advanced Photon Source was supported by the U.S. Department of Energy, Basic Energy Sciences, Office of Science, under Contract No. W-31-109-Eng-38.
- The Actinide Facility was supported by the Division of Chemical Sciences, Office of Basic Energy Sciences, U. S. Department of Energy under contracts W-31-109-Eng-38 and DE-AC03-76SF00098

XAS Experimental

HandlingRadioactiveMaterial

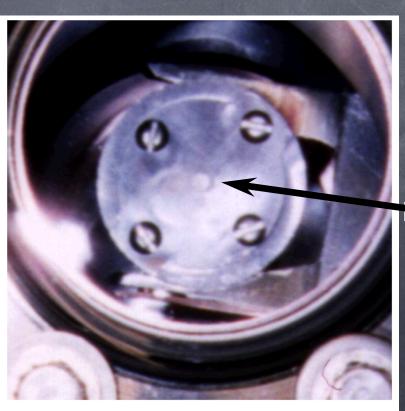


Shipping Under Vacuum

- Battery Operated Ion Pump
 - Shipping Documents Pu 1 page
 - Shipping Documents Excide Lead Acid Battery 26 pages

Plutonium

Disk

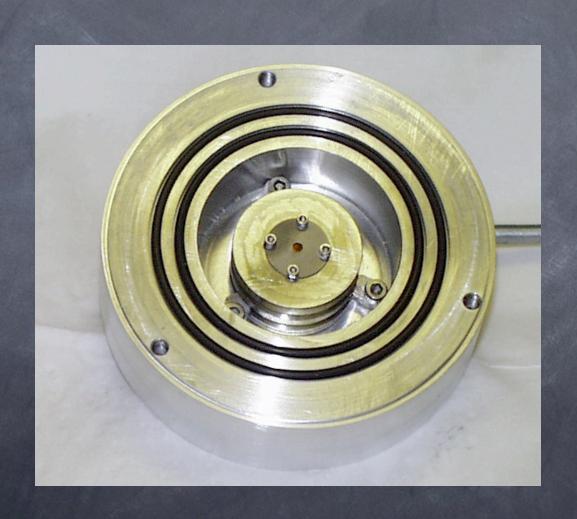


Plutonium Disk

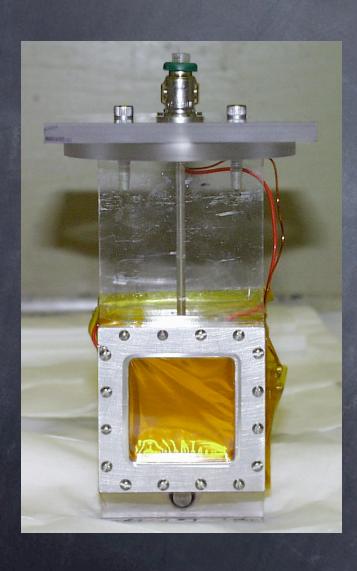
Before Sputter

After Sputter

Sealed Ar Container



Measurement Cells



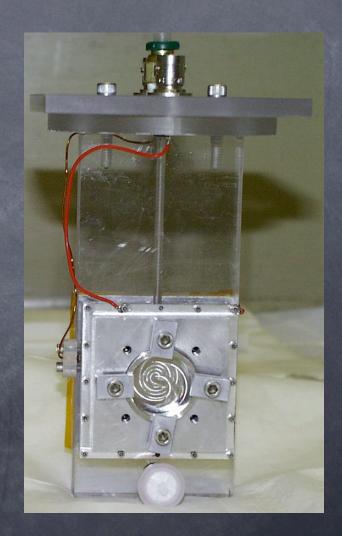
Why E-Yield?

FluorescenceYield Too

Large Kapton Window
 Allows for Simultaneous
 F-Yield Measurement

Details

- Sample Sealed With Indium Wire and Mutiple Kapton Layers
- System Filled With He for Electron Amplification

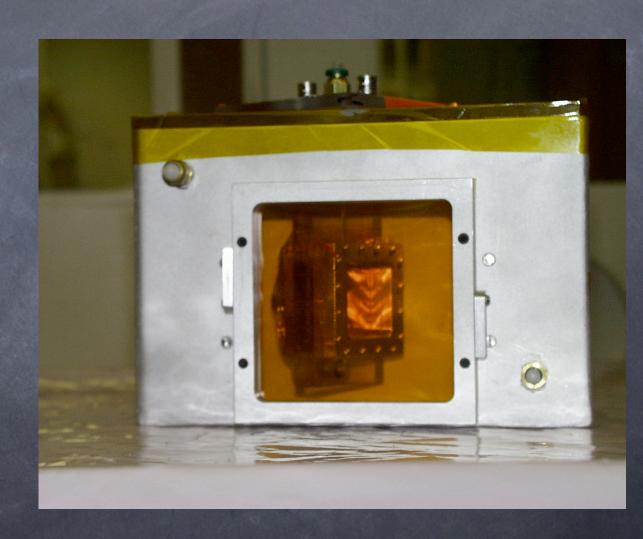


Sample Biased -50 V

BEAM LINE CONTAINMENT

Kapton Sealed Container

- Three Large Windows
 - One Large Window In Front (Allows FY Light to Detector)
 - One on Each Side to Light Beam Into and Out of Cell
- Containment VesselHolds Room Air



OLANL

- Repeated Sputter-Anneal Cycles
 to Remove Dissolved O₂
- Samples Transferred to Vacuum Transfer Vessel

Shipping

Samples Shipped in Vacuum Transfer Vessel at 10⁻⁸ Torr

ALS

- Final Cleaning Done in Sample Handling and Integrated Transfer System for Pu Intense Light Experiments
 - Sputter 5 kV Ar ions
 - Anneal 75 °C

SURFACE PREPARATION

